

**isc Silicon PNP Power Transistor**
**BD250/A/B/C**
**DESCRIPTION**

- Collector Current  $-I_C = -25A$
- Collector-Emitter Breakdown Voltage-  
:  $V_{(BR)CEO} = -45V(\text{Min})$ - BD250;  $-60V(\text{Min})$ - BD250A  
 $-80V(\text{Min})$ - BD250B;  $-100V(\text{Min})$ - BD250C
- Complement to Type BD249/A/B/C
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**APPLICATIONS**

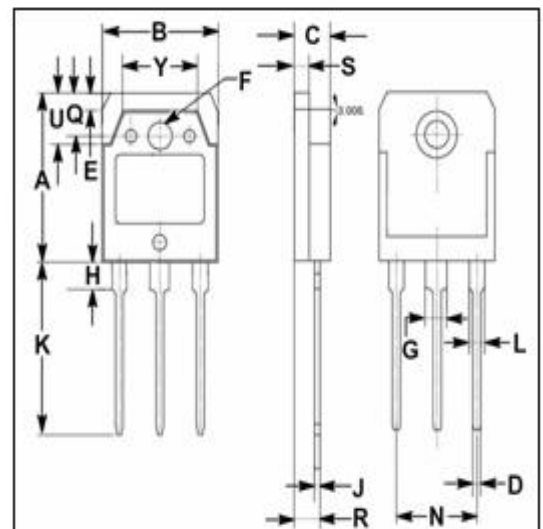
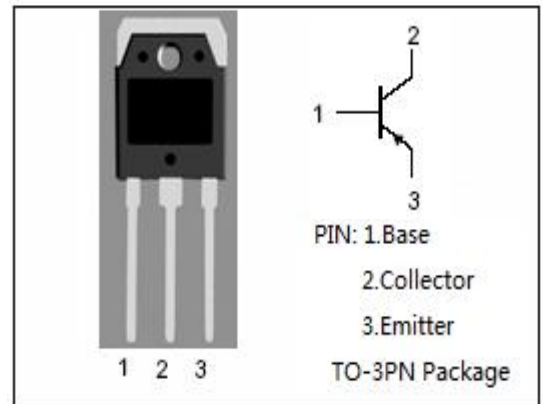
- Designed for use in general purpose power amplifier and switching applications

**ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )**

| SYMBOL    | PARAMETER  | VALUE   | UNIT             |   |
|-----------|--|---------|------------------|---|
| $V_{CER}$ | Collector-Emitter Voltage ( $R_{BE} = 100 \Omega$ )  | BD250   | -55              | V |
|           |  | BD250A  | -70              |   |
|           |  | BD250B  | -90              |   |
|           |  | BD250C  | -115             |   |
| $V_{CEO}$ | Collector-Emitter Voltage                            | BD250   | -45              | V |
|           |  | BD250A  | -60              |   |
|           |  | BD250B  | -80              |   |
|           |  | BD250C  | -100             |   |
| $V_{EBO}$ | Emitter-Base Voltage                                 | -5      | V                |   |
| $I_C$     | Collector Current-Continuous                         | -25     | A                |   |
| $I_{CM}$  | Collector Current-Peak                               | -40     | A                |   |
| $I_B$     | Base Current   | -5      | A                |   |
| $P_C$     | Collector Power Dissipation @ $T_a=25^\circ\text{C}$ | 3       | W                |   |
|           | Collector Power Dissipation @ $T_c=25^\circ\text{C}$ | 125     |                  |   |
| $T_J$     | Junction Temperature                                 | 150     | $^\circ\text{C}$ |   |
| $T_{stg}$ | Storage Temperature Range                            | -65~150 | $^\circ\text{C}$ |   |

**THERMAL CHARACTERISTICS**

| SYMBOL        | PARAMETER                            | MAX | UNIT               |
|---------------|--------------------------------------|-----|--------------------|
| $R_{th\ j-c}$ | Thermal Resistance, Junction to Case | 1.0 | $^\circ\text{C/W}$ |



| DIM | mm    |       |
|-----|-------|-------|
|     | MIN   | MAX   |
| A   | 19.60 | 20.30 |
| B   | 15.50 | 15.70 |
| C   | 4.70  | 4.90  |
| D   | 0.90  | 1.10  |
| E   | 1.90  | 2.10  |
| F   | 3.40  | 3.60  |
| G   | 2.90  | 3.20  |
| H   | 3.20  | 3.40  |
| J   | 0.595 | 0.605 |
| K   | 19.80 | 20.70 |
| L   | 1.90  | 2.20  |
| N   | 10.89 | 10.91 |
| Q   | 4.90  | 5.10  |
| R   | 3.35  | 3.45  |
| S   | 1.995 | 2.100 |
| U   | 5.90  | 6.20  |
| Y   | 9.90  | 10.10 |

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**BD250/A/B/C**
**ELECTRICAL CHARACTERISTICS**

 T<sub>C</sub>=25°C unless otherwise specified

| SYMBOL                 | PARAMETER                            | CONDITIONS  | MIN   | TYP.   | MAX  | UNIT |    |
|------------------------|--------------------------------------|---|---|--|------|------|----|
| V <sub>(BR)CEO</sub>   | Collector-Emitter Breakdown Voltage  | BD250   | I <sub>C</sub> = -30mA; I <sub>B</sub> = 0  |  |      | V    |    |
|                        |                                      | BD250A  |   | -45  |      |      |    |
|                        |                                      | BD250B  |   | -60  |      |      |    |
|                        |                                      | BD250C  |   | -80  |      |      |    |
| V <sub>CE(sat)-1</sub> | Collector-Emitter Saturation Voltage | I <sub>C</sub> = -15A; I <sub>B</sub> = -1.5A   |   |  | -1.8 | V    |    |
| V <sub>CE(sat)-2</sub> | Collector-Emitter Saturation Voltage | I <sub>C</sub> = -25A; I <sub>B</sub> = -5A   |   |  | -4.0 | V    |    |
| V <sub>BE(on)-1</sub>  | Base-Emitter On Voltage              | I <sub>C</sub> = -15A; V <sub>CE</sub> = -4V  |   |  | -2.0 | V    |    |
| V <sub>BE(on)-2</sub>  | Base-Emitter On Voltage              | I <sub>C</sub> = -25A; V <sub>CE</sub> = -4V  |   |  | -4.0 | V    |    |
| I <sub>CES</sub>       | Collector Cutoff Current             | BD250   | V <sub>CE</sub> = -55V; V <sub>BE</sub> = 0 |  |      | -0.7 | mA |
|                        |                                      | BD250A  |   | V <sub>CE</sub> = -70V; V <sub>BE</sub> = 0  |      |      |    |
|                        |                                      | BD250B  |   | V <sub>CE</sub> = -90V; V <sub>BE</sub> = 0  |      |      |    |
|                        |                                      | BD250C  |   | V <sub>CE</sub> = -115V; V <sub>BE</sub> = 0 |      |      |    |
| I <sub>CEO</sub>       | Collector Cutoff Current             | BD250/A   | V <sub>CE</sub> = -30V; I <sub>B</sub> = 0  |  |      | -1.0 | mA |
|                        |                                      | BD250B/C  |   | V <sub>CE</sub> = -60V; I <sub>B</sub> = 0   |      |      |    |
| I <sub>EBO</sub>       | Emitter Cutoff Current               | V <sub>EB</sub> = -5V; I <sub>C</sub> = 0   |   |  | -1.0 | mA   |    |
| h <sub>FE-1</sub>      | DC Current Gain                      | I <sub>C</sub> = -1.5A; V <sub>CE</sub> = -4V   | 25  |  |      |      |    |
| h <sub>FE-2</sub>      | DC Current Gain                      | I <sub>C</sub> = -15A; V <sub>CE</sub> = -4V  | 10  |  |      |      |    |
| h <sub>FE-3</sub>      | DC Current Gain                      | I <sub>C</sub> = -25A; V <sub>CE</sub> = -4V  | 5   |  |      |      |    |
| Switching times        |                                      |   |   |  |      |      |    |
| t <sub>on</sub>        | Turn-on Time                         | I <sub>C</sub> = -5A; I <sub>B1</sub> = -I <sub>B2</sub> = -0.5A;<br>R <sub>L</sub> = 5 Ω; V <sub>BE(off)</sub> = -5V |   | 0.2  |      | μs   |    |
| t <sub>off</sub>       | Turn-off Time                        |   |   |  | 0.4  |      | μs |

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